



Atty Docket No.: TKHR4540

Serial No.: 09/467,675

H20/D

3/12/03  
Jma Th

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

In re application of :  
Application No. : 09/467,675  
Filed : December 21, 1999  
For : Structure For ESD Protection With Single Crystal Silicon Sided Junction  
Applicant : Liou et al.  
Examiner : Ori Nadav  
Art Unit : 2811

**AMENDMENT AND RESPONSE TO OFFICE ACTION**

Assistant Commissioner of Patents and Trademarks  
Washington, DC 20231

Sir:

In response to the Office Action dated September 30, 2002, please consider the following remarks.

**In The Claims:**

Please substitute the following clean text claims for the pending claims having the same number.

*SAC 21*  
1. (Thrice Amended) An ESD protection structure having a single crystal Si-sided diode used to protect an internal circuit, the ESD protection structure electrically connected between an input pad and a node and the internal circuit electrically connected to the node, the ESD protection structure comprising:

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